

RFLNAM18-10 is a three-stage Low Noise Amplifier that operates from 12 - 18 GHz and can be used in low-power Ku band applications or to drive the high-power amplifier. The amplifier provides 21 dB small signal gain and 21 dBm of Output P1dB. The input and output are matched to 50 ohms with on-chip DC blocking capacitors. The device is specifically designed for use in 12 - 18 GHz frequency in point-to-point radios for cellular backhaul Applications, 5G RF transceivers & SATCOM. The technology used to design LNA is 0.1um GaAs pHEMT Process. Results are shown in the datasheet with all parasitic & coupling effects at the desired frequency.

Features:

- RF Frequency: 12-18 GHz
- Noise Figure of 1.8 dB
- Small Signal Gain of 21 dB
- OP1dB of 20.5 dBm
- OIP3 of 28.5 dBm
- Biasing: VDD=4V, VGG=-0.5V, ID= 100mA
- Die Size: 1.15 mm x 1.85 mm.

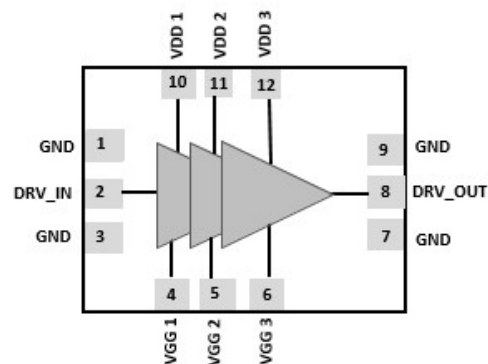
Application:

- 5G mobile system.
- Satellite Communication.
- Point-to-point communication system.
- Terrestrial communication system.
- Radar Application

Tech Specs:

- Part Number: RFLNAM18-10
- Provider: RFIC Solutions Inc.
- Foundry node: 0.1um GaAs pHEMT Win Semiconductors
- Porting: IP can be ported to 65nm Si / CMOS node
- Maturity: IC is fabricated and tested.
- Availability: Now

Functional Block Diagram:



Deliverables:

- Schematic and Netlist
- Abstract Model (.lib file)
- Layout View(Optional)
- Behavioral model (Circuit & EM simulation)
- Extracted View(Optional)
- GDSII
- DRC, LVS, Antenna report
- Test bench with configuration(Optional)
- Documentation

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